Product data sheet

1. General description

Standard reverse recovery power diode in a TO247-2L package.

2. Features and benefits

- Low forward voltage drop
- Low leakage current
- High voltage capability
- · High inrush current capability

3. Applications

- · Input rectifier
- Bypass diode

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Val	ues		Unit
Absolute	maximum rating						
V_{RRM}	repetitive peak reverse voltage			16	000		V
I _{F(AV)}	average forward current	δ = 0.5 ; square-wave pulse; $T_{mb} \le 130$ °C; Fig. 1; Fig. 2; Fig. 3	60			Α	
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	950 1045			Α	
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse				Α	
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static ch	aracteristics						
V _F	forward voltage	I _F = 60 A; T _j = 25 °C; <u>Fig. 6</u>		-	1.07	1.12	V
		I _F = 60 A; T _j = 150 °C; <u>Fig. 6</u>		-	0.99	1.05	V

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		и I/I л
2	А	anode		K A 001aaa020
mb	mb	mounting base; connected to cathod	K A TO247-2L	

6. Ordering information

Table 3. Ordering information

Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
WND60P16W	TO247-2L	WND60P16WQ	Tube	30	TO247L-2L	10-Nov-2020

7. Marking

Table 4. Marking codes

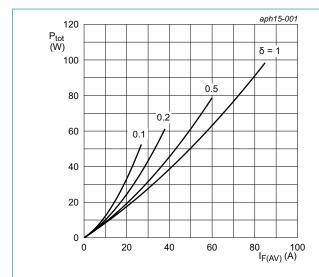
Type number	Marking codes
WND60P16W	D60P16

8. Limiting values

Table 5. Limiting values

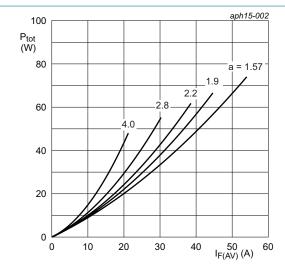
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V_{RRM}	repetitive peak reverse voltage		1600	V
V_{RWM}	crest working reverse voltage		1600	V
V_R	reverse voltage	DC	1600	V
$I_{F(AV)}$	average forward current	$δ = 0.5$; square-wave pulse; $T_{mb} \le 130$ °C; Fig. 1; Fig. 2; Fig. 3	60	А
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	950	А
		t_p = 8.3 ms; $T_{J(init)}$ = 25 °C; sine-wave pulse	1045	А
l ² t	I ² t for fusing	SIN; t _p = 10 ms	4513	A ² s
T _{stg}	storage temperature		-55 to 150	°C
T _j	junction temperature		150	°C



$$\begin{split} I_{F(AV)} &= I_{F(RMS)} \times \sqrt{\delta} \\ V_o &= 0.792 \text{ V; } R_s = 0.0043 \text{ } \Omega \end{split}$$

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



a = form factor = $I_{F(RMS)}/I_{F(AV)}$ V_o = 0.792 V; R_s = 0.0043 Ω

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

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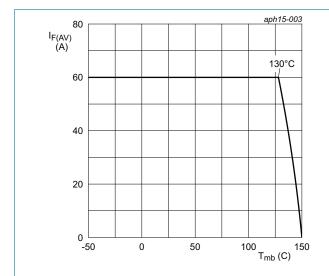


Fig. 3. Forward current as a function of mounting base temperature; maximum values

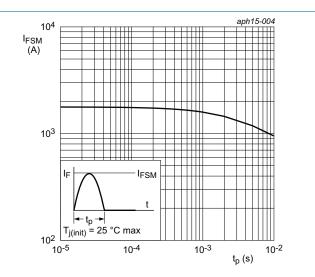


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values

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9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th(j-mb)}}$	thermal resistance from junction to mounting base	Fig. 5	-	-	0.25	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air	-	40	-	K/W

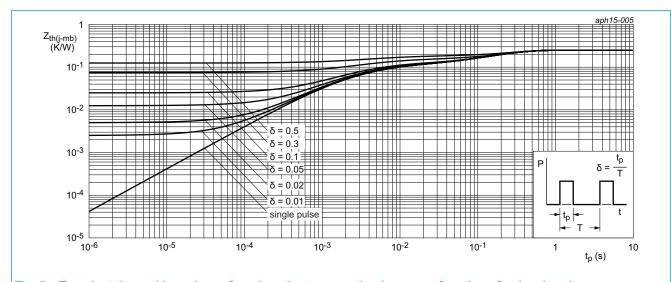
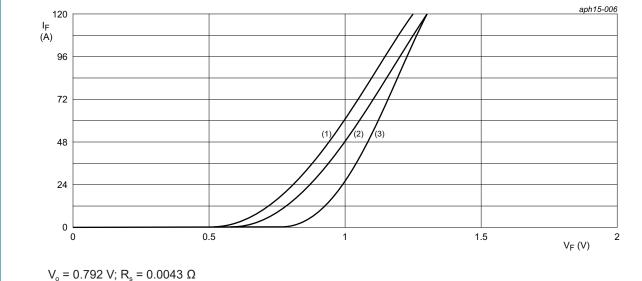


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
V _F	forward current	I _F = 60 A; T _j = 25 °C; <u>Fig. 6</u>	-	1.07	1.12	V
		I _F = 60 A; T _j = 150 °C; <u>Fig. 6</u>	-	0.99	1.05	V
I _R	reverse current	V _R = 1600 V; T _j = 25 °C	-	-	50	μΑ
		V _R = 1600 V; T _j = 150 °C	-	-	1.5	mA

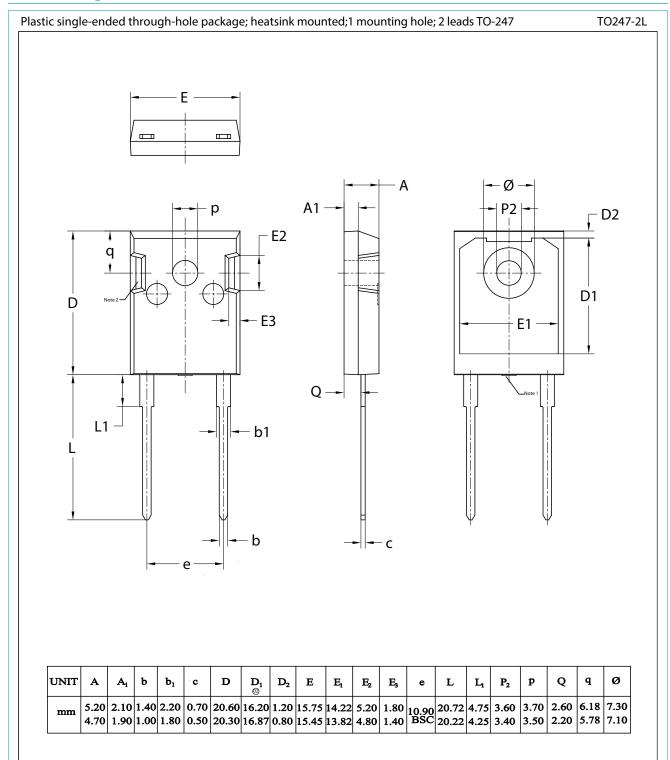


(1) $T_j = 150$ °C; typical values (2) $T_j = 150$ °C; maximum values

(3) $T_i = 25$ °C; maximum values

Fig. 6. Forward current as a function of forward voltage

11. Package outline



Note:

- 1. Mold resin protrusion max 0.127mm.
- 2. Metal exposed with Sn plating.

12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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